NP50P03YDG

MOS FIELD EFFECT TRANSISTOR

R07DS0019EJ0200
Rev.2.00
Mar 16, 2011

Description

The NP50P03YDG is P-channel MOS Field Effect Transistor designed for high current switching applications.

Features

- Low on-state resistance
  — $R_{DS(on)}$ = 8.4 mΩ MAX. (V_{GS} = –10 V, I_D = –25 A)
- Low C_{iss}: C_{iss} = 2300 pF TYP. (V_{DS} = –25 V, V_{GS} = 0 V)
- Designed for automotive application and AEC-Q101 qualified
- Small size package 8-pin HSON

Ordering Information

Part No.	LEAD PLATING	PACKING	Package
NP50P03YDG -E1-AY *1	Pure Sn (Tin)	Tape 2500 p/reel	8-pin HSON, Taping (E1 type)
NP50P03YDG -E2-AY *1			8-pin HSON, Taping (E2 type)

Note: *1. Pb-free (This product does not contain Pb in the external electrode.)

Absolute Maximum Ratings (T_A = 25°C)

Item	Symbol	Ratings	Unit
Drain to Source Voltage (V_{GS} = 0 V)	V_{DSS}	–30	V
Gate to Source Voltage (V_{DS} = 0 V)	V_{GSS}	∓20	V
Drain Current (DC) (T_C = 25°C)	$I_{D(DC)}$	∓50	A
Drain Current (pulse) *1	$I_{D(pulse)}$	∓200	A
Total Power Dissipation (T_C = 25°C)	P_{T1}	102	W
Total Power Dissipation (T_A = 25°C) *2	P_{T2}	1.0	W
Channel Temperature	T_{ch}	175	°C
Storage Temperature	T_{stg}	–55 to +175	°C
<R> Single Avalanche Current *3	I_{AS}	24	A
<R> Single Avalanche Energy *3	E_{AS}	58	mJ

Thermal Resistance

Channel to Case Thermal Resistance	$R_{th(ch-C)}$	1.47	°C/W
Channel to Ambient Thermal Resistance *2	$R_{th(ch-A)}$	150	°C/W

Notes: *1. T_C = 25°C, PW ≤ 10 μs, Duty Cycle ≤ 1%
*2. Mounted on glass epoxy substrate of 40 mm x 40 mm x 0.8 mmt
<R> *3. Starting T_{ch} = 25°C, V_{DD} = –15 V, R_G = 25 Ω, L = 100 μH, V_{GS} = –20 → 0 V

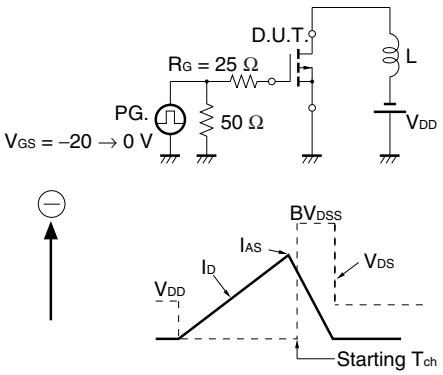
The mark <R> shows major revised points.
The revised points can be easily searched by copying an "<R>" in the PDF file and specifying it in the "Find what:" field.

Electrical Characteristics (T_A = 25°C)

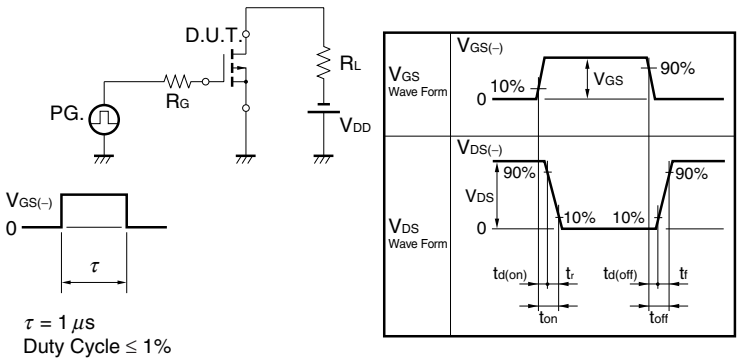
Item	Symbol	Min	Typ	Max	Unit	Test Conditions
Zero Gate Voltage Drain Current	I_{DSS}			–1	μA	V_{DS} = –30 V, V_{GS} = 0 V
Gate Leakage Current	I_{GSS}			∓100	nA	V_{GS} = ∓20 V, V_{DS} = 0 V
Gate to Source Threshold Voltage	$V_{GS(th)}$	–1.0	–1.6	–2.5	V	V_{DS} = V_{GS}, I_D = –250 μA
Forward Transfer Admittance *1	$\|y_{fs}\|$	23	46		S	V_{DS} = –5 V, I_D = –25 A
Drain to Source On-state Resistance *1	$R_{DS(on)1}$		6.7	8.4	mΩ	V_{GS} = –10 V, I_D = –25 A
	$R_{DS(on)2}$		8.5	13	mΩ	V_{GS} = –5 V, I_D = –25 A
Input Capacitance	C_{iss}		2300	3500	pF	V_{DS} = –25 V,
Output Capacitance	C_{oss}		440	660	pF	V_{GS} = 0 V,
Reverse Transfer Capacitance	C_{rss}		320	580	pF	f = 1 MHz
Turn-on Delay Time	$t_{d(on)}$		9	19	ns	V_{DD} = –15 V, I_D = –25 A,
Rise Time	t_r		7	16	ns	V_{GS} = –10 V,
Turn-off Delay Time	$t_{d(off)}$		230	470	ns	R_G = 0 Ω
Fall Time	t_f		180	440	ns	
Total Gate Charge	Q_G		64	96	nC	V_{DD} = –24 V,
Gate to Source Charge	Q_{GS}		9		nC	V_{GS} = –10 V,
Gate to Drain Charge	Q_{GD}		21		nC	I_D = –50 A
Body Diode Forward Voltage *1	$V_{F(S-D)}$		1.0	1.5	V	I_F = –50 A, V_{GS} = 0 V
Reverse Recovery Time	t_{rr}		49		ns	I_F = –50 A, V_{GS} = 0 V,
Reverse Recovery Charge	Q_{rr}		44		nC	di/dt = 100 A/μs

Note: *1. Pulsed

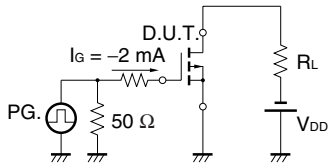
TEST CIRCUIT 1 AVALANCHE CAPABILITY



TEST CIRCUIT 2 SWITCHING TIME

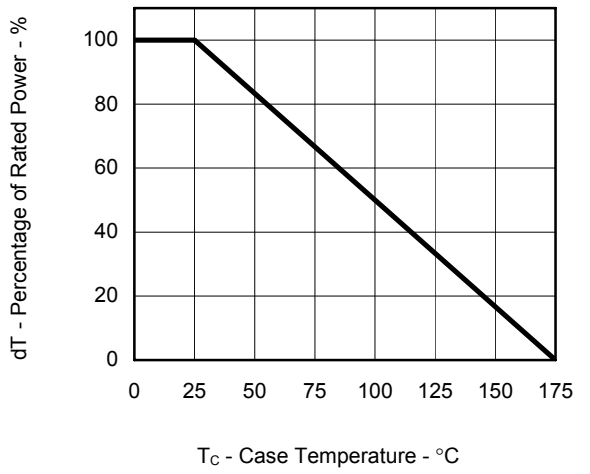


TEST CIRCUIT 3 GATE CHARGE

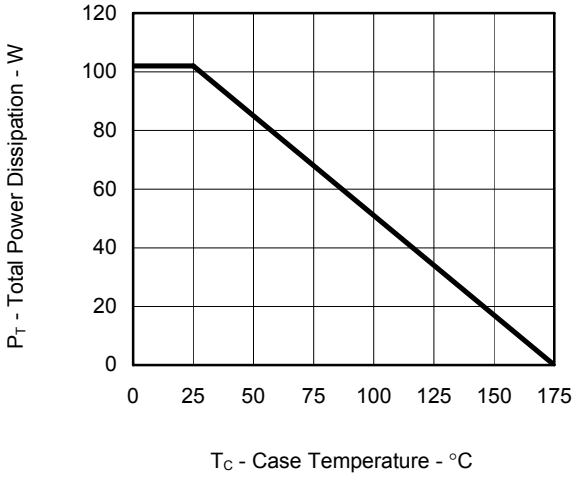


Typical Characteristics (T_A = 25°C)

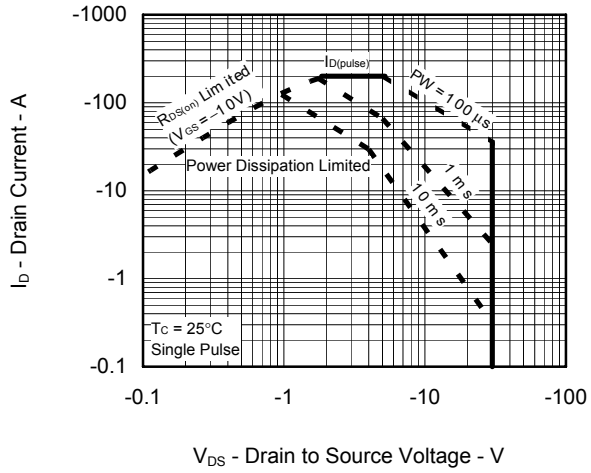
DERATING FACTOR OF FORWARD BIAS SAFE OPERATING AREA



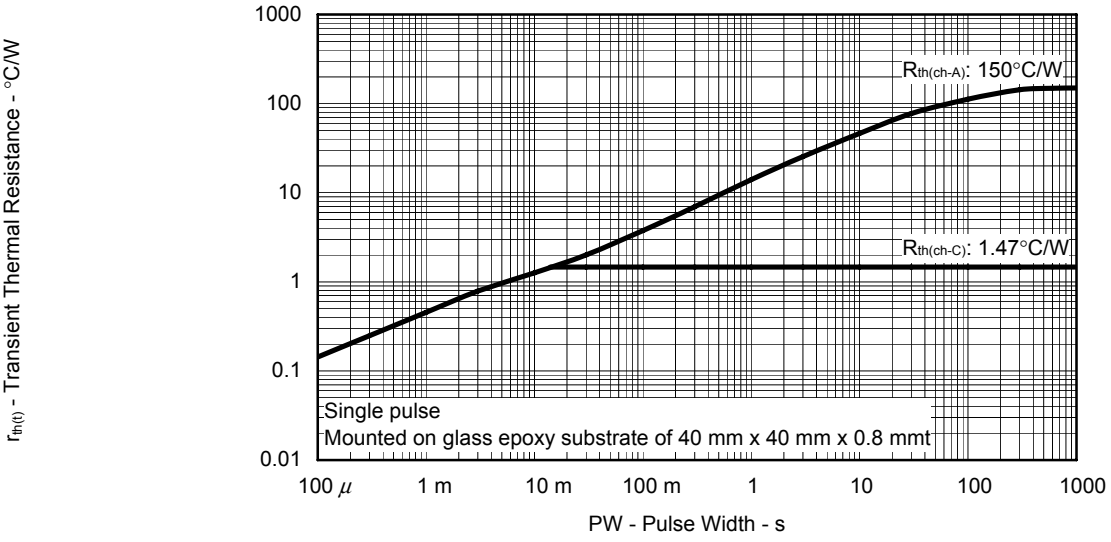
TOTAL POWER DISSIPATION vs. CASE TEMPERATURE



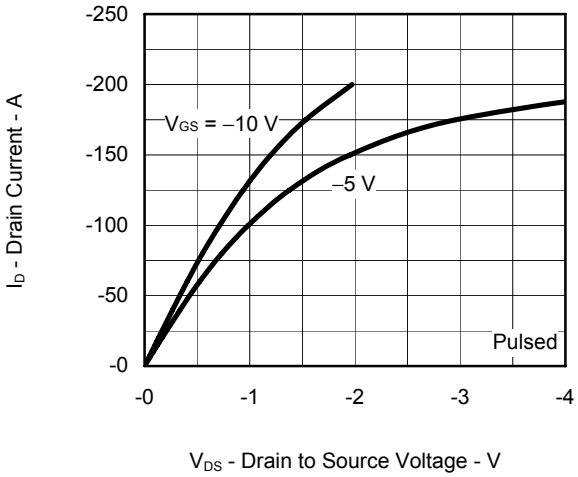
FORWARD BIAS SAFE OPERATING AREA



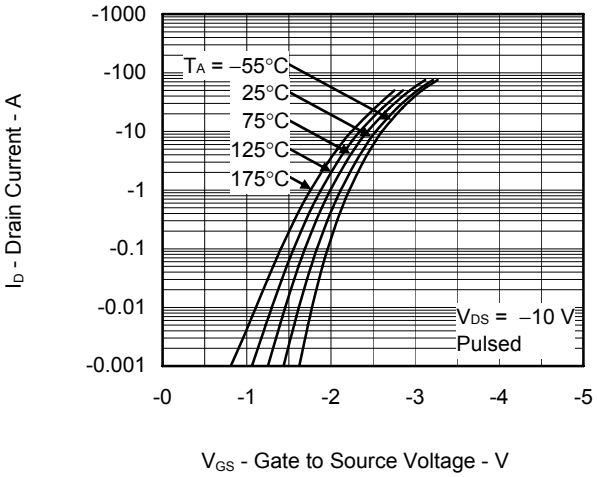
TRANSIENT THERMAL RESISTANCE vs. PULSE WIDTH



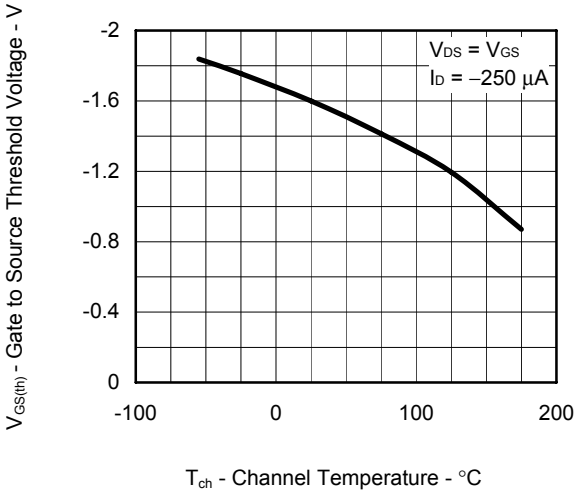
DRAIN CURRENT vs.
DRAIN TO SOURCE VOLTAGE



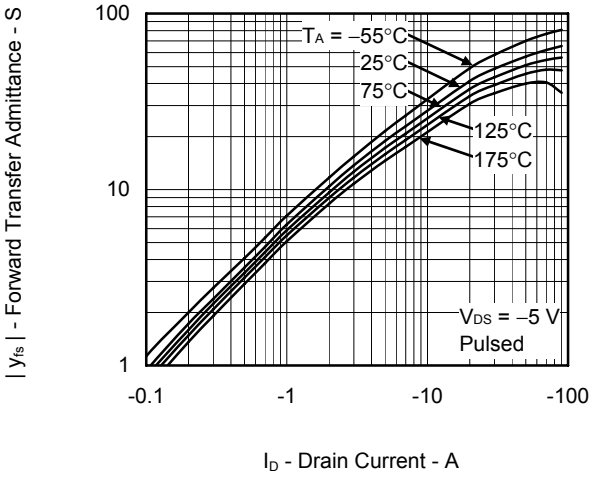
FORWARD TRANSFER CHARACTERISTICS



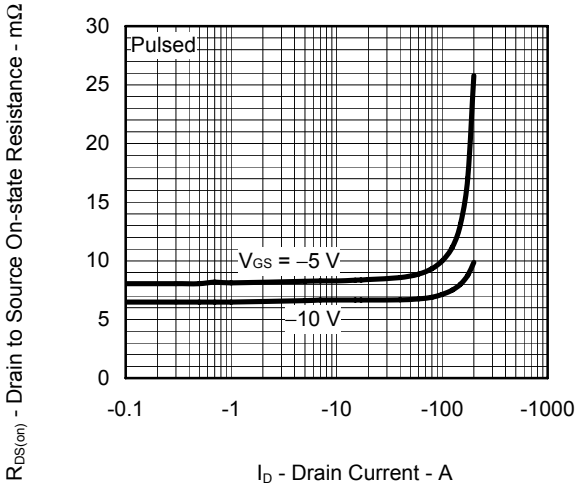
GATE TO SOURCE THRESHOLD VOLTAGE
vs. CHANNEL TEMPERATURE



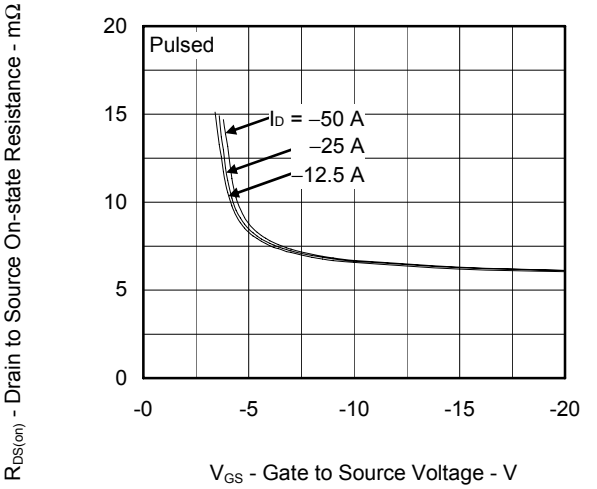
FORWARD TRANSFER ADMITTANCE vs. DRAIN CURRENT



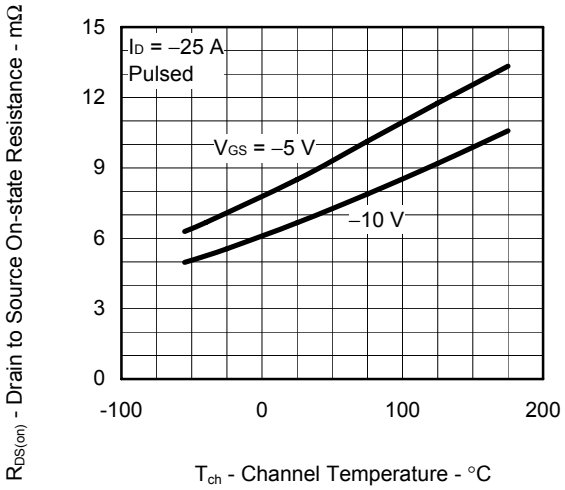
DRAIN TO SOURCE ON-STATE RESISTANCE vs.
DRAIN CURRENT



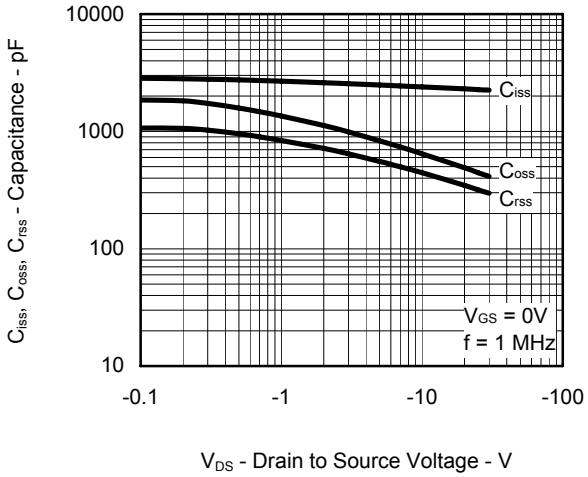
DRAIN TO SOURCE ON-STATE RESISTANCE vs.
GATE TO SOURCE VOLTAGE



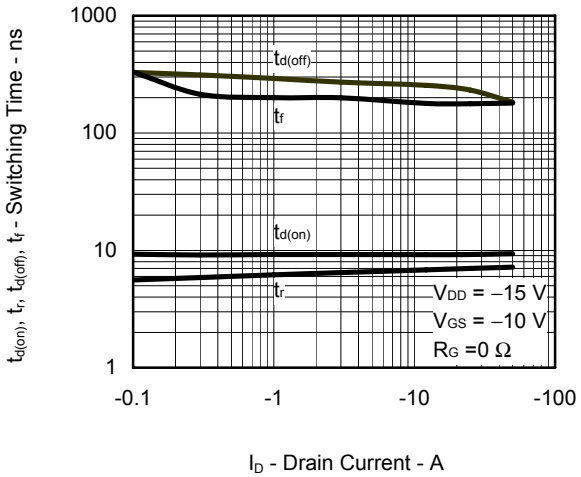
DRAIN TO SOURCE ON-STATE RESISTANCE vs. CHANNEL TEMPERATURE



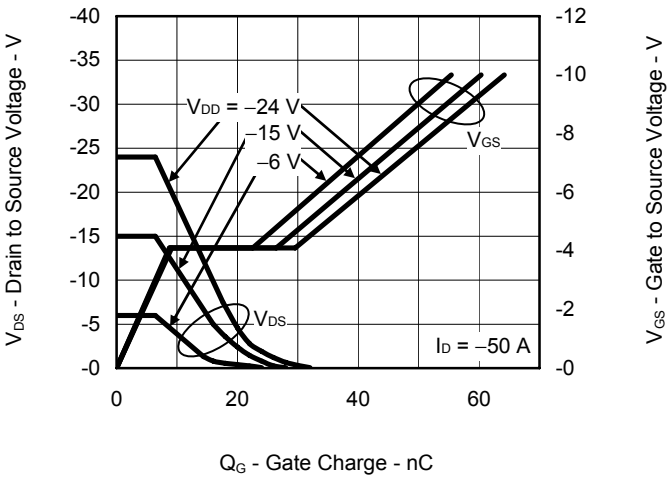
CAPACITANCE vs. DRAIN TO SOURCE VOLTAGE



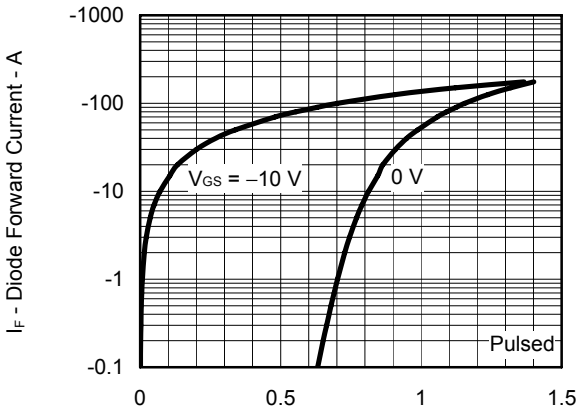
SWITCHING CHARACTERISTICS



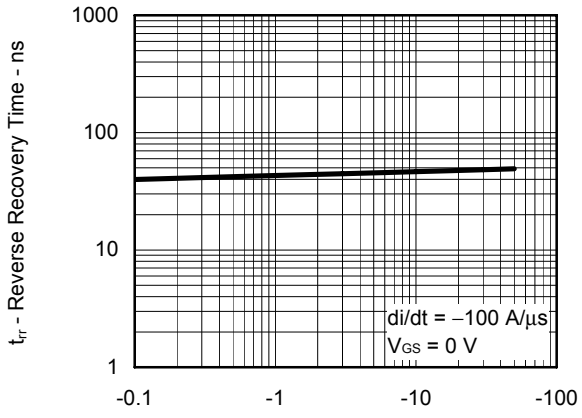
DYNAMIC INPUT/OUTPUT CHARACTERISTICS



SOURCE TO DRAIN DIODE FORWARD VOLTAGE

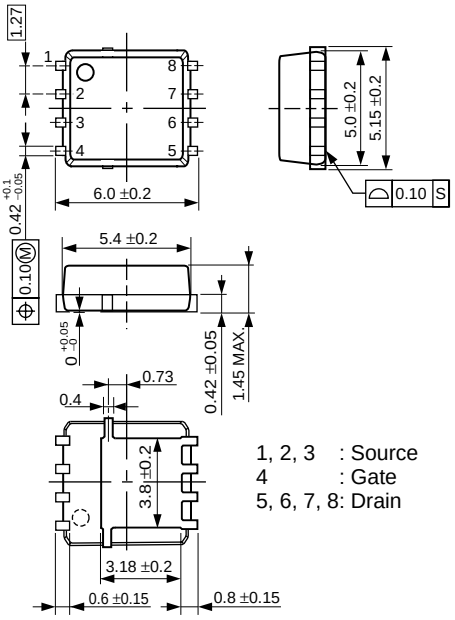


REVERSE RECOVERY TIME vs. DRAIN CURRENT

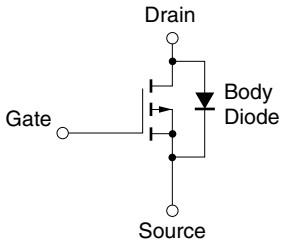


Package Drawings (Unit: mm)

8-pin HSON (Mass: 0.13 g TYP.)



Equivalent Circuit



Remark Strong electric field, when exposed to this device, can cause destruction of the gate oxide and ultimately degrade the device operation. Steps must be taken to stop generation of static electricity as much as possible, and quickly dissipate it once, when it has occurred.

Revision History	NP50P03YDG Data Sheet

Rev.	Date	Description	
		Page	Summary
1.00	Jul 01, 2010	–	First Edition Issued
2.00	Mar 16, 2011	p.1	Repetitive Avalanche Current -> Single Avalanche Current Repetitive Avalanche Energy -> Single Avalanche Energy Modification of Note *3

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Renesas Electronics America Inc.
2880 Scott Boulevard Santa Clara, CA 95050-2554, U.S.A.
Tel: +1-408-588-6000, Fax: +1-408-588-6130

Renesas Electronics Canada Limited
1101 Nicholson Road, Newmarket, Ontario L3Y 9C3, Canada
Tel: +1-905-898-5441, Fax: +1-905-898-3220

Renesas Electronics Europe Limited
Dukes Meadow, Millboard Road, Bourne End, Buckinghamshire, SL8 5FH, U.K
Tel: +44-1628-585-100, Fax: +44-1628-585-900

Renesas Electronics Europe GmbH
Arcadiastrasse 10, 40472 Düsseldorf, Germany
Tel: +49-211-65030, Fax: +49-211-6503-1327

Renesas Electronics (China) Co., Ltd.
7th Floor, Quantum Plaza, No.27 ZhiChunLu Haidian District, Beijing 100083, P.R.China
Tel: +86-10-8235-1155, Fax: +86-10-8235-7679

Renesas Electronics (Shanghai) Co., Ltd.
Unit 204, 205, AZIA Center, No.1233 Lujiazui Ring Rd., Pudong District, Shanghai 200120, China
Tel: +86-21-5877-1818, Fax: +86-21-6887-7858 / -7898

Renesas Electronics Hong Kong Limited
Unit 1601-1613, 16/F., Tower 2, Grand Century Place, 193 Prince Edward Road West, Mongkok, Kowloon, Hong Kong
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7F, No. 363 Fu Shing North Road Taipei, Taiwan
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